Analog Power AM4922N

## N-Channel 20-V (D-S) MOSFET

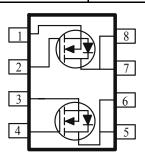
These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

•	Low r <sub>DS(on)</sub> Provides Higher Efficiency and
	Extends Battery Life

- Miniature SO-8 Surface Mount Package Saves Board Space
- High power and current handling capability
- Low side high current DC-DC Converter applications

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$I_{DS}$ (V) $r_{DS(on)}$ $m(\Omega)$ $I_{D}$ (A			
20	$22 @ V_{GS} = 4.5V$	7.8		
20	$28 @ V_{GS} = 2.5V$	7.0		





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			20	V	
Gate-Source Voltage		$V_{GS}$	±8	V	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	Τ_	7.8		
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	П	6.4	A	
Pulsed Drain Current <sup>b</sup>			±50		
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	2.3	A	
D	$T_A=25^{\circ}C$	D	2.0	W	
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	rD	1.3		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units	
Marina and Landian da Analisada	t <= 10 sec	D	62.5	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	$\kappa_{ m  heta JA}$	110	°C/W

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#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Damana 4a u		T C . 1111	Limits			TT *4	
Parameter	Symbol Test Conditions		Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	0.7				
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			±100	nA	
Zana Cata Valta aa Duain Cumant	IDSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uА	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = \pm 8 \text{ V}$	20			A	
D i G G D i A	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 6.5 \text{ A}$			22	mΩ	
Drain-Source On-Resistance <sup>A</sup>		$V_{GS} = 2.5 \text{ V}, I_D = 5.8 \text{ A}$			28		
Forward Tranconductance <sup>A</sup>	gs	$V_{DS} = 15 \text{ V}, I_D = 6.5 \text{ A}$		40		S	
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 6.5 \text{ A}$		5.5		nC	
Gate-Source Charge	Qgs			1.0			
Gate-Drain Charge	Qgd			1.4		1	
Turn-On Delay Time	td(on)			20			
Rise Time	t <sub>r</sub>	$V_{\rm DD} = 25 \text{ V}, R_{\rm L} = 25 \Omega, I_{\rm D} = 1 \text{ A},$ $V_{\rm GEN} = 10 \text{ V}$		9		nS	
Turn-Off Delay Time	td(off)			70			
Fall-Time	tf			20			

#### Notes

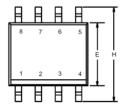
- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

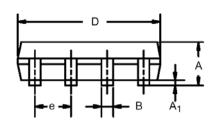
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# Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INC	HES
Dim	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
е	1.27	BSC	0.050	BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°

